

Switchmode Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features:

- *High Surge Capacity
- *Low Power Loss, High efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- *High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- *Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives
- *The marking is indicated by part no. with. "M". ex:SF56M



MAXIMUM RATINGS

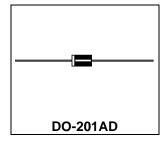
Characteristic	Symbol	SF56M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{R50}	400	٧
RMS Reverse Voltage	VR _(RMS)	280	٧
Average Rectifier Forward Current	Io	5.0	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase,60Hz)	I _{FSM}	75	А
Operating and Storage Junction Temperature Range	T _J , T _{STG}	-65 to +150	$^{\circ}\!\mathbb{C}$

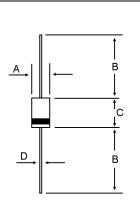
FLECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage (I_F =5.0 Amp, T_C = 25 $^{\circ}$ C) (I_F =5.0 Amp, T_C = 125 $^{\circ}$ C)	V _F		1.17 1.02	1.30	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R		0.02 5	5.0 	uA
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A)	Trr			50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР		45		₽F

ULTRAFAST RECTIFIERS

5.0 AMPERES **400 VOLTS**





DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	5.00	5.60		
В	25.40			
С	8.50	9.50		
D	1.18	1.22		

CASE---Transfer molded plastic

POLARITY---Cathode indicated polarity band



FIG-1 TYPICAL FORWARD CHARACTERSTICS

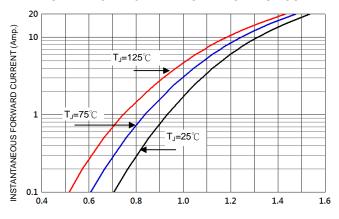
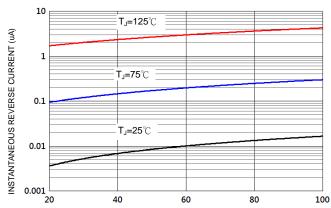
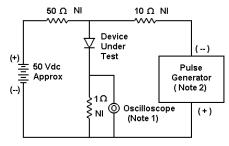


FIG-2 TYPICAL REVERSE CHARACTERISTICS

FORWARD VOLTAGE (Volts)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)



- 1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

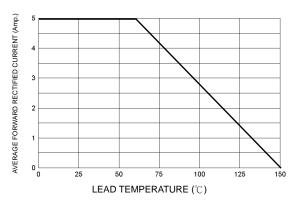


FIG-4TYPICAL JUNCTION CAPACITANCE

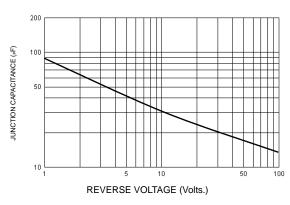
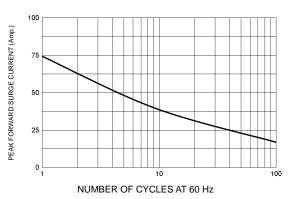
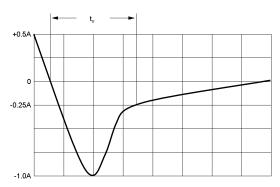


FIG-5PEAK FORWARD SURGE CURRENT





Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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